Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Glass
Overall Length:
4.200 millimeters
Terminal Length:
25.000 millimeters
Overall Diameter:
2.000 millimeters
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
Do-35
Electrode Internally-electrically Connected To Case:
Cathode
Mounting Method:
Terminal
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
5.9 regulator voltage
Current Rating Per Characteristic:
20.00 milliamperes source cutoff current horsepower metric
Power Rating Per Characteristic:
500.0 milliwatts small-signal input power, common-collector preset
Maximum Operating Tempurature Per Measurement Point:
175.0 degrees celsius junction
Terminal Type And Quantity:
2 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0